SN74LS365A, SN74LS367A, SN74LS368A

3-State Hex Buffers

These devices are high speed hex buffers with 3-state outputs. They are organized as single 6-bit or 2-bit/4-bit, with inverting or non-inverting data (D) paths. The outputs are designed to drive 15 TTL Unit Loads or 60 Low Power Schottky loads when the Enable (E) is LOW.

When the Output Enable (E) is HIGH, the outputs are forced to a high impedance "off" state. If the outputs of the 3-state devices are tied together, all but one device must be in the high impedance state to avoid high currents that would exceed the maximum ratings. Designers should ensure that Output Enable signals to 3-state devices whose outputs are tied together are designed so there is no overlap.

GUARANTEED OPERATING RANGES

Symbol	Parameter	Min	Typ	Max	Unit
V_{CC}	Supply Voltage	4.75	5.0	5.25	V
T_A	Operating Ambient Temperature Range	0	25	70	°C
I_{OH}	Output Current – High			–2.6	mA
I_{OL}	Output Current – Low			24	mA

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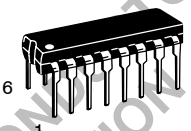
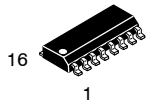
LOW POWER SCHOTTKY



PLASTIC
N SUFFIX
CASE 648

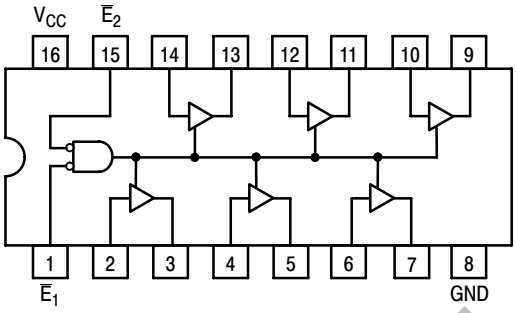


SOIC
D SUFFIX
CASE 751B

ORDERING INFORMATION

Device	Package	Shipping
SN74LS365AN	16 Pin DIP	2000 Units/Box
SN74LS365AD	SOIC–16	38 Units/Rail
SN74LS365ADR2	SOIC–16	2500/Tape & Reel
SN74LS367AN	16 Pin DIP	2000 Units/Box
SN74LS367AD	SOIC–16	38 Units/Rail
SN74LS367ADR2	SOIC–16	2500/Tape & Reel
SN74LS368AN	16 Pin DIP	2000 Units/Box
SN74LS368AD	SOIC–16	38 Units/Rail
SN74LS368ADR2	SOIC–16	2500/Tape & Reel

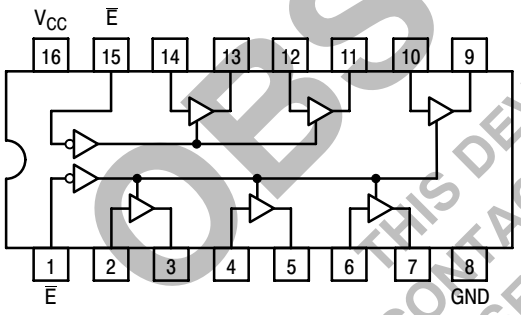
SN74LS365A
HEX 3-STATE BUFFER WITH
COMMON 2-INPUT NOR ENABLE



TRUTH TABLE

INPUTS			OUTPUT
$\overline{E}_1$	$\overline{E}_2$	D	
L	L	L	L
L	L	H	H
H	X	X	(Z)
X	H	X	(Z)

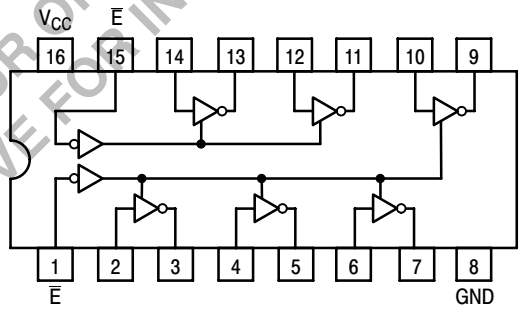
SN74LS367A
HEX 3-STATE BUFFER
SEPARATE 2-BIT AND 4-BIT SECTIONS



TRUTH TABLE

INPUTS		OUTPUT
$\overline{E}$	D	
L	L	L
L	H	H
H	X	(Z)

SN74LS368A
HEX 3-STATE INVERTER BUFFER
SEPARATE 2-BIT AND 4-BIT SECTIONS



TRUTH TABLE

INPUTS		OUTPUT
$\overline{E}$	D	
L	L	H
L	H	L
H	X	(Z)

DC CHARACTERISTICS OVER OPERATING TEMPERATURE RANGE (unless otherwise specified)

Symbol	Parameter	Limits			Unit	Test Conditions	
		Min	Typ	Max			
V_{IH}	Input HIGH Voltage	2.0			V	Guaranteed Input HIGH Voltage for All Inputs	
V_{IL}	Input LOW Voltage			0.8	V	Guaranteed Input LOW Voltage for All Inputs	
V_{IK}	Input Clamp Diode Voltage		−0.65	−1.5	V	V_{CC} = MIN, I_{IN} = −18 mA	
V_{OH}	Output HIGH Voltage	2.4	3.1		V	V_{CC} = MIN, I_{OH} = MAX, V_{IN} = V_{IH} or V_{IL} per Truth Table	
V_{OL}	Output LOW Voltage		0.25	0.4	V	I_{OL} = 12 mA	V_{CC} = V_{CC} MIN, V_{IN} = V_{IL} or V_{IH} per Truth Table
			0.35	0.5	V	I_{OL} = 24 mA	
I_{OZH}	Output Off Current HIGH			20	μA	V_{CC} = MAX, V_{OUT} = 2.7 V	
I_{OZL}	Output Off Current LOW			−20	μA	V_{CC} = MAX, V_{OUT} = 0.4 V	
I_{IH}	Input HIGH Current			20	μA	V_{CC} = MAX, V_{IN} = 2.7 V	
				0.1	mA	V_{CC} = MAX, V_{IN} = 7.0 V	
I_{IL}	Input LOW Current $\overline{E}$ Inputs			−0.4	mA	V_{CC} = MAX, V_{IN} = 0.4 V	
	D Inputs			−20	μA	V_{CC} = MAX, V_{IN} = 0.5 V Either $\overline{E}$ Input at 2.0 V	
				−0.4	mA	V_{CC} = MAX, V_{IN} = 0.4 V Both $\overline{E}$ Inputs at 0.4 V	
I_{OS}	Short Circuit Current (Note 1)	−40		−225	mA	V_{CC} = MAX	
I_{CC}	Power Supply Current LS365A, 367A			24	mA	V_{CC} = MAX	
	LS368A			21			

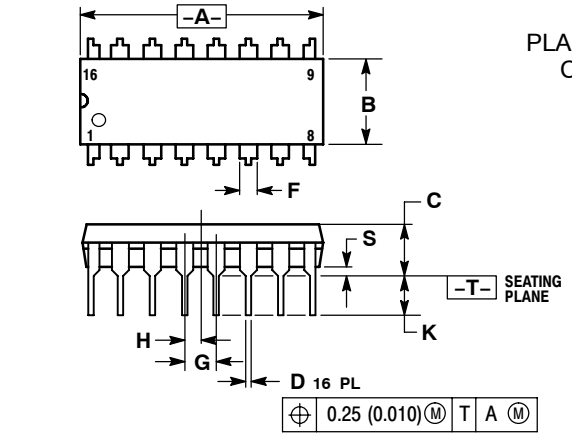
Note 1: Not more than one output should be shorted at a time, nor for more than 1 second.

AC CHARACTERISTICS (T_A = 25°C, V_{CC} = 5.0 V)

Symbol	Parameter	Limits						Unit	Test Conditions
		LS365A/LS367A			LS366A/LS368A				
		Min	Typ	Max	Min	Typ	Max		
t_{PLH} t_{PHL}	Propagation Delay		10 9.0	16 22		7.0 12	15 18	ns	C_L = 45 pF, R_L = 667 Ω
t_{PZH} t_{PZL}	Output Enable Time		19 24	35 40		18 28	35 45	ns	
t_{PHZ} t_{PLZ}	Output Disable Time			30 35			32 35	ns	C_L = 5.0 pF

PACKAGE DIMENSIONS

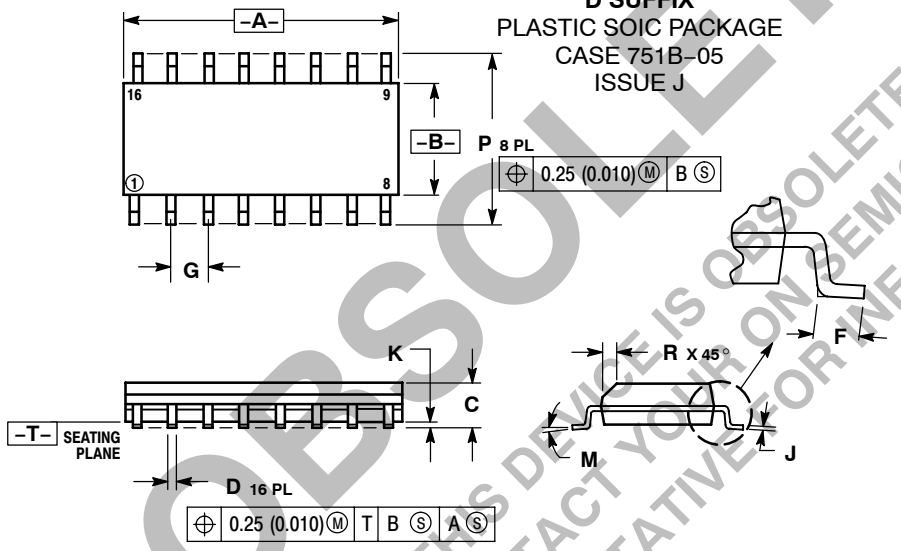
N SUFFIX
PLASTIC PACKAGE
CASE 648–08
ISSUE R



NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. DIMENSION L TO CENTER OF LEADS WHEN FORMED PARALLEL.
4. DIMENSION B DOES NOT INCLUDE MOLD FLASH.
5. ROUNDED CORNERS OPTIONAL.

	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
A	0.740	0.770	18.80	19.55
B	0.250	0.270	6.35	6.85
C	0.145	0.175	3.69	4.44
D	0.015	0.021	0.39	0.53
F	0.040	0.70	1.02	1.77
G	0.100 BSC		2.54 BSC	
H	0.050 BSC		1.27 BSC	
J	0.008	0.015	0.21	0.38
K	0.110	0.130	2.80	3.30
L	0.295	0.305	7.50	7.74
M	0 °	10 °	0 °	10 °
S	0.020	0.040	0.51	1.01

D SUFFIX
PLASTIC SOIC PACKAGE
CASE 751B–05
ISSUE J



NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION.
4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.

	MILLIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
A	9.80	10.00	0.386	0.393
B	3.80	4.00	0.150	0.157
C	1.35	1.75	0.054	0.068
D	0.35	0.49	0.014	0.019
F	0.40	1.25	0.016	0.049
G	1.27 BSC		0.050 BSC	
J	0.19	0.25	0.008	0.009
K	0.10	0.25	0.004	0.009
M	0 °	7 °	0 °	7 °
P	5.80	6.20	0.229	0.244
R	0.25	0.50	0.010	0.019

PUBLICATION ORDERING INFORMATION

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